

Composite Transistor For high speed switching Silicon N-channel MOSFET

DESCRIPTION

RT3K44M is a composite transistor built with two INK0010AX chips in SC-88 package.

FEATURE

 $\mbox{\cdot} Input$ impedance is high, and not necessary to consider a drive

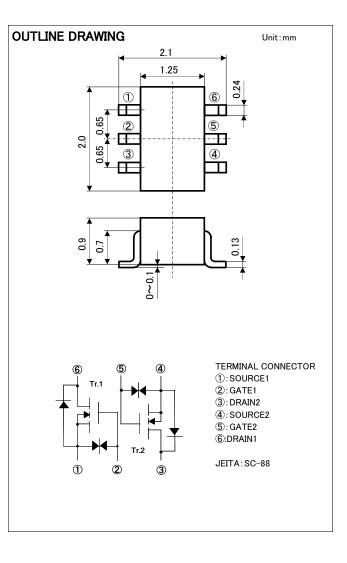
- electric current.
- •Drive voltage 4V
- Low on Resistance.

 $R_{DS(ON)}{=}4.0\,\Omega\,(\text{TYP})\,@ID{=}100mA,\,VGS{=}4.0V$

- $R_{DS(ON)}=3.0\,\Omega\,(\text{TYP})\;@ID=100mA,\;VGS=10V$
- •High speed switching.
- •Small package for easy mounting.

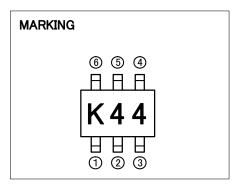
APPLICATION

High speed switching , Analog switching



MAXIMUM RATING (Ta=25°C) (Tr1,Tr2 Common)

SYMBOL	PARAMETER	RATING	UNIT
Vdss	Drain-source voltage	60	V
Vgss	Gate-source voltage	±20	V
ID	Drain current(DC)	100	mA
I DP	Drain current(Pulse)	400(※1)	mA
PD	Total power dissipation	150	mW
Tch	Channel temperature	+150	°C
Tstg	Range of Storage temperature	-55 ~ +150	ů



 $1: Pw \leq 10 \mu s$, Duty cycle $\leq 1\%$

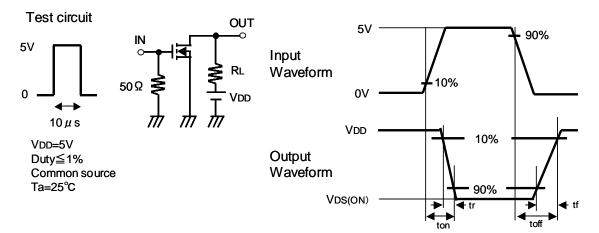
RT3K44M

Composite Transistor For high speed switching Silicon N-channel MOSFET

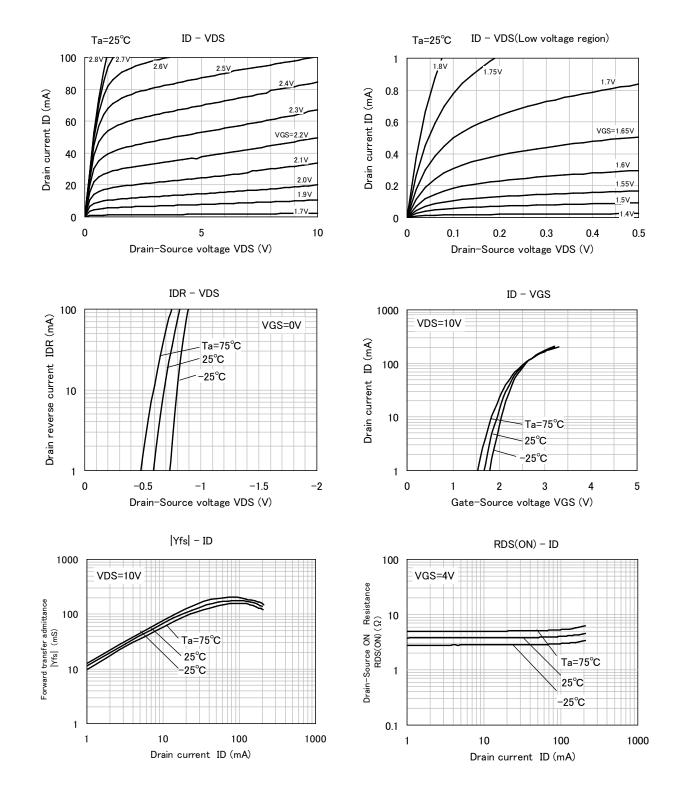
ELECTRICAL CHARACTERISTICS (Ta=25°C) (Tr1,Tr2 Common)

Symbol	Parameter	Test conditions	Limits			
			Min	Тур	Max	Unit
V(BR)DSS	Drain-source breakdown voltage	ID=100µA, VGS=0V	60	-	-	٧
Igss	Gate-source leak current	$V_{GS}=\pm 15V$, $V_{DS}=0V$	-	-	±1.0	μA
Idss	Zero gate voltage drain current	VDS=60V, VGS=0V	-	-	1.0	μA
Vth	Gate threshold voltage	ID=250µA, VDS=VGS	1.0	-	2.0	V
Y _{fs}	Forward transfer admittance	VDS=10V, ID=100mA	-	200	-	mS
RDS(ON)	Static drain-source on-state resistance	ID=100mA, VGS=4.0V	-	4.0	-	Ω
		ID=100mA, VGS=10.0V	-	3.0	-	
Ciss	Input capacitance	VDS=10V, VGS=0V, f=1MHz	-	20	-	pF
Coss	Output capacitance		-	5.0	-	
ton	Switching time	VDD=5V, ID=10mA VGS=0~5V	-	27	-	ns
toff			-	58	-	

Switching time test condition



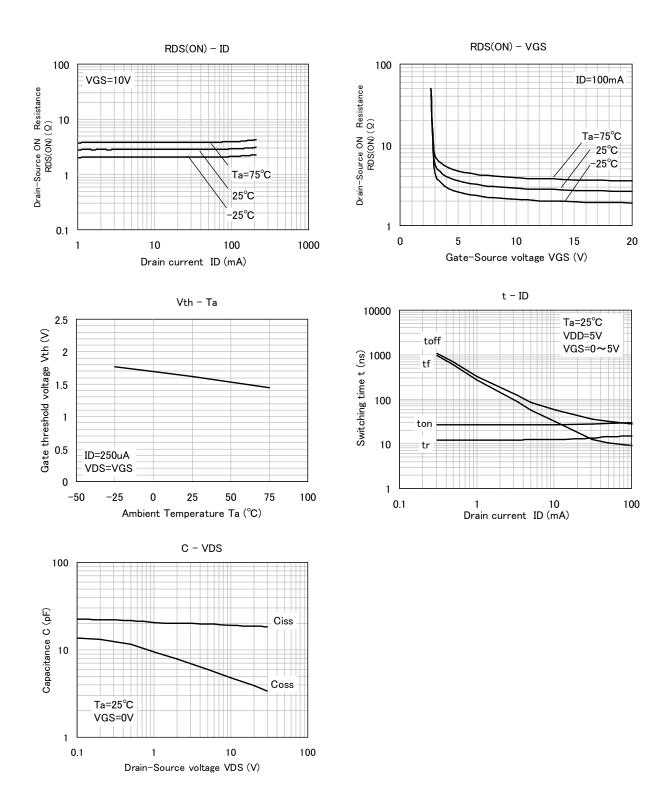
RT3K44M Composite Transistor For high speed switching Silicon N-channel MOSFET



TYPICAL CHARACTERISTICS(Tr1,Tr2 Common)

RT3K44M

Composite Transistor For high speed switching Silicon N-channel MOSFET



ISAHAYA ELECTRONICS CORPORATION

Keep safety first in your circuit designs!

-ISAHAYA Electronics Corporation puts the maximum effort into making semiconductor products better and more reliable, but there is always the possibility that trouble may occur with them. Trouble with semiconductors may lead to personal injury, fire or property damage. Remember to give due consideration to safety when making your circuit designs, with appropriate measures such as (1) placement of substitutive, auxiliary, (2) use of non-farmable material or (3) prevention against any malfunction or mishap.

Notes regarding these materials

•These materials are intended as a reference to our customers in the selection of the ISAHAYA products best suited to the customer' s application; they don't convey any license under any intellectual property rights, or any other rights, belonging ISAHAYA or third party. •ISAHAYA Electronics Corporation assumes no responsibility for any damage, or infringement of any third party's rights, originating in the use of any product data, diagrams, charts or circuit application examples contained in these materials.

All information contained in these materials, including product data, diagrams and charts, represent information on products at the time of publication of these materials, and are subject to change by ISAHAYA Electronics Corporation without notice due to product improvements or other reasons. It is therefore recommended that customers contact ISAHAYA Electronics Corporation or an authorized ISAHAYA products distributor for the latest product information before purchasing product listed herein.

ISAHAYA Electronics Corporation products are not designed or manufactured for use in a device or system that is used under circumstances in which human life is potentially at stake. Please contact ISAHAYA Electronics Corporation or an authorized ISAHAYA products distributor when considering the use of a product contained herein for any specific purposes, such as apparatus or systems for transportation, vehicular, medical, aerospace, nuclear, or undersea repeater use.

•The prior written approval of ISAHAYA Electronics Corporation is necessary to reprint or reproduce in whole or in part these materials. •If these products or technologies are subject to the Japanese export control restrictions, they must be exported under a license from the Japanese government and cannot be imported into a country other than the approved destination. Any diversion or re-export contrary to the export control laws and regulations of Japan and/or the country of destination is prohibited.

Please contact ISAHAYA Electronics Corporation or authorized ISAHAYA products distributor for further details on these materials or the products contained therein.